

# SPONTANEOUS HALL EFFECT AND TEXTURE OF MICROCRYSTALLINE Fe—Si—Sb ALLOYS<sup>1)</sup>

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The spontaneous Hall effect and the grain texture of microcrystalline Fe—6 wt. % Si—0.08 wt. % Sb alloys were studied. The effect of the tensile stress was investigated too.

## 1. INTRODUCTION

The microcrystalline Fe—Si alloys of increased silicon content prepared by a rapid quenching roll method in ribbon form have excellent magnetic properties such as high permeability, low hysteresis losses, low magnetostriction and high electrical resistivity [1, 2, 3]. As the silicon content increases to 6 wt. %, the massive material becomes brittle, but a planar flow technique permits a ductile ribbons elaboration.

It is known that the addition of a small amount of antimony is effective for developing the preferred (110) [001] texture and the (100) texture in grain oriented silicon steel [4, 5]. Therefore it is interesting to investigate microcrystalline Fe—Si alloys with a small amount of Sb.

## II. EXPERIMENTAL PROCEDURE AND RESULTS

The rapidly quenched Fe—6.0 wt. % Si—0.08 wt. % Sb alloys were prepared by a singleroll method on a steel wheel under an argon atmosphere. The starting alloy material was made from pure electrolytic iron (99.99 %), pure silicon (99.999 %) and Fe, Sb, intermetallic compounds. The ribbon size obtained was  $\sim 35 \mu\text{m}$  in thickness and  $\sim 12 \text{ mm}$  in width.

Grain diameter measurements were made by optical micrography on the ribbon surface after mechanical polishing and etching. The average grain size

was  $8 \mu\text{m}$  for as cast ribbon and about  $100 \mu\text{m}$  for ribbon annealed at  $1100^\circ\text{C}$  for 60 minutes in argon. After the annealing of ribbons a columnar structure of grains on the cross section was observed, while for as cast ribbons the dendritic structure was observed. A typical microstructure of ribbons in the as-quenched state is shown in Figs. 1 and 2. Fig. 3 shows that the grains grew across the whole width of ribbons annealed at  $1100^\circ\text{C}$  for 60 minutes.

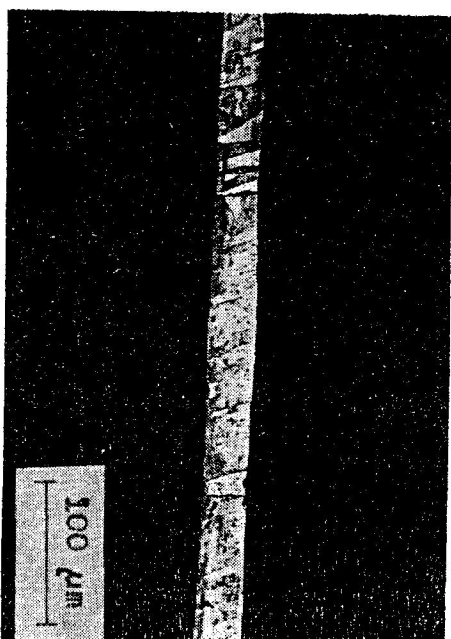


Fig. 1. Microstructure of Fe—6% Si ribbon (as quenched state, cross section, magnif.  $200\times$ )

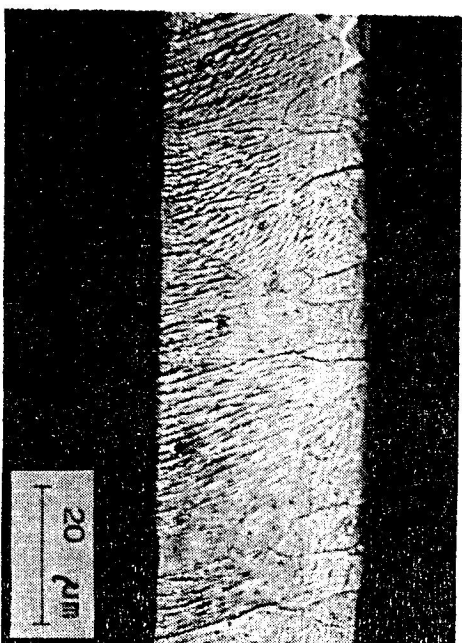


Fig. 2. Micrograph of Fe—6% Si ribbon (as quenched state, detail of the cross section, magnif.  $1000\times$ )

The grain texture was investigated by X-ray pole figure measurements. From a (200) and (110) pole figure analysis by computer some expressive maxima of an Orientation Distribution Function (ODF<sub>max</sub>) of grains were determined.

These maxima for annealed Fe—Si and Fe—Si—Sb ribbons are shown in Table 1.

The Hall resistivity  $\rho_H$  in ferromagnetic materials may be written as

$$\rho_H = U \cdot \frac{d}{l} = R_0 B + \mu_0 M (R_1 - R_0 N),$$

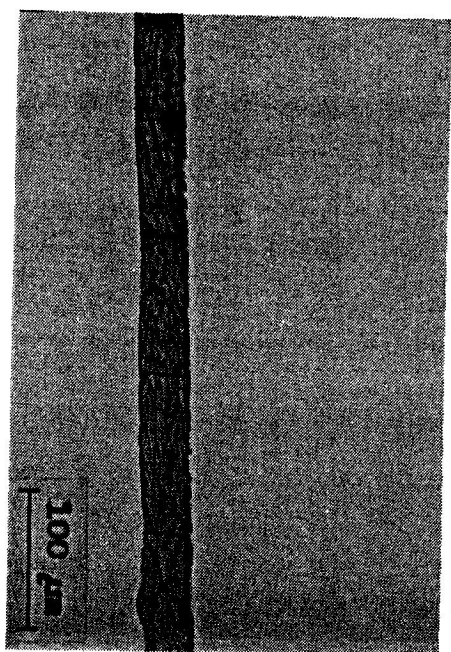


Fig. 3. Microstructure of Fe—6% Si ribbon after annealing at 1100°C for 60 minutes in argon (magnif. 200×)

Table 1

The maxima of orientation distribution function of grains for annealed Fe—Si and Fe—Si—Sb ribbons.

(hkl)	[uvw]	Fe—Si ODF max.	Fe—Si—Sb ODF max.
001	100	6.2	9.7
001	011	18.6	29.7

where  $U$  is the Hall voltage,  $d$  the thickness of the specimen,  $l$  the electrical current,  $B$  the applied magnetic induction,  $M$  the magnetization,  $N$  the demagnetization factor (assumed equal to  $\approx 1$  for our geometry),  $R_0$  and  $R_1$  are the ordinary and extraordinary Hall coefficients, respectively; and  $R_1 = R_0 + R_s$ , where  $R_s$  is the spontaneous Hall coefficient. The ordinary effect ( $R_0$ ) arises from the Lorentz force and the spontaneous effect ( $R_s$ ) is due to the scattering of spin-polarized carriers through spin-orbit interactions from impurities and phonons.

Room-temperature measurements of the Hall effect were carried out with ordinary dc method (using a constant-current source, nanovoltmeter and mini-computer) with the possibility of tensile stress application. The Hall voltages were recorded as a function of the applied field at the constant tensile stress  $f$ . For  $T < T_c$  ( $T_c$  is Curie temperature) there is  $R_1 \gg R_0$  and  $R_1 \approx R_s$  may be determined by the initial slope  $\left(\frac{\partial \rho_H}{\partial B}\right)_{B=0}$  [6, 7].

Table 2

Tensile stress dependence of the spontaneous Hall coefficient  $R_s$  for annealed Fe—Si—Sb alloys.

$f \cdot 3 \times 10^{-8}$ [Pa]	$R_s$ [ $10^{-10} \text{ m}^3 \cdot \text{A}^{-1} \cdot \text{s}^{-1}$ ]
0	1.89
1	1.86
2	1.84
3	1.82

The change of the spontaneous Hall coefficient  $R_s$  with tensile stress  $f$  for our annealed Fe—Si—Sb alloys are very small as can be seen in Table 2. The spontaneous Hall coefficient is closely connected with real electronic structure [6, 8]. When a tensile stress is applied parallel to the long axis of the Fe—Si—Sb ribbon, a deformation of the lattice may occur and this may lead to the change of the electronic structure. These effects can explain the observed small decrease of the coefficient  $R_s$  when the tensile stress increases.

### III. CONCLUSIONS

The grain texture produced by a rapidly rolling ribbon is similar to the rolled texture of conventional silicon steel. The existence of the cubic (001) [100] texture in microcrystalline alloys probably leads to better magnetic properties at high inductions than in the conventional grain oriented steel [3]. We attribute the measured changes of spontaneous the Hall coefficient  $R_s$  with the tensile stress to the changes of the electronic structure due to the deformation of the lattice in our microcrystalline Fe—Si—Sb alloys.

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# СПОНТАННЫЙ ЭФФЕКТ ХОЛЛА И СТРУКТУРА МИКРОКРИСТАЛЛИЧЕСКИХ Fe—Si—Sb СПЛАВОВ

В работе изучается спонтанный эффект Холла и зернистая структура микрокристаллических Fe—Si—Sb сплавов. Наряду с этим рассматривается влияние растягивающего напряжения.